

74AVCH1T45

Dual supply translating transceiver; 3-state

Rev. 02 — 5 May 2009

Product data sheet

1. General description

The 74AVCH1T45 is a single bit, dual supply transceiver that enables bidirectional level translation. It features two data input-output ports (A and B), a direction control input (DIR) and dual supply pins ($V_{CC(A)}$ and $V_{CC(B)}$). Both $V_{CC(A)}$ and $V_{CC(B)}$ can be supplied at any voltage between 0.8 V and 3.6 V making the device suitable for translating between any of the low voltage nodes (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V and 3.3 V). Pins A and DIR are referenced to $V_{CC(A)}$ and pin B is referenced to $V_{CC(B)}$. A HIGH on DIR allows transmission from A to B and a LOW on DIR allows transmission from B to A.

The device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing any damaging backflow current through the device when it is powered down. In suspend mode when either $V_{CC(A)}$ or $V_{CC(B)}$ are at GND level, both A and B are in the high-impedance OFF-state.

The 74AVCH1T45 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

2. Features

- Wide supply voltage range:
 - ◆ $V_{CC(A)}$: 0.8 V to 3.6 V
 - ◆ $V_{CC(B)}$: 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-12 (0.8 V to 1.3 V)
 - ◆ JESD8-11 (0.9 V to 1.65 V)
 - ◆ JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114E Class 3B exceeds 8000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101C exceeds 1000 V
- Maximum data rates:
 - ◆ 500 Mbit/s (1.8 V to 3.3 V translation)
 - ◆ 320 Mbit/s (< 1.8 V to 3.3 V translation)
 - ◆ 320 Mbit/s (translate to 2.5 V or 1.8 V)
 - ◆ 280 Mbit/s (translate to 1.5 V)

- ◆ 240 Mbit/s (translate to 1.2 V)
- Suspend mode
- Bus hold on data inputs
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | Version |
|--------------|---|-------|--|---------|
| | Temperature range | Name | Description | |
| 74AVCH1T45GW | $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ | SC-88 | plastic surface-mounted package; 6 leads | SOT363 |
| 74AVCH1T45GM | $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1.45 \times 0.5\text{ mm}$ | SOT886 |

4. Marking

Table 2. Marking

| Type number | Marking code ^[1] |
|--------------|-----------------------------|
| 74AVCH1T45GW | K5 |
| 74AVCH1T45GM | K5 |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

Fig 1. Logic symbol

Fig 2. Logic diagram

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|--------------------|-----|-------------------------------|
| V _{CC(A)} | 1 | supply voltage port A and DIR |
| GND | 2 | ground (0 V) |
| A | 3 | data input or output |
| B | 4 | data input or output |
| DIR | 5 | direction control |
| V _{CC(B)} | 6 | supply voltage port B |

7. Functional description

Table 4. Function table^[1]

| Supply voltage | Input | Input/output ^[2] | |
|---|--------------------|-----------------------------|-------|
| V _{CC(A)} , V _{CC(B)} | DIR ^[3] | A | B |
| 0.8 V to 3.6 V | L | A = B | input |
| 0.8 V to 3.6 V | H | input | B = A |
| GND ^[4] | X | Z | Z |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] The input circuit of the data I/O is always active.

[3] The DIR input circuit is referenced to V_{CC(A)}.

[4] If at least one of V_{CC(A)} or V_{CC(B)} is at GND level, the device goes into Suspend mode.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------|-------------------------|-------------------------------|----------------|-----------------|------|
| $V_{CC(A)}$ | supply voltage A | | -0.5 | +4.6 | V |
| $V_{CC(B)}$ | supply voltage B | | -0.5 | +4.6 | V |
| I_{IK} | input clamping current | $V_I < 0$ V | -50 | - | mA |
| V_I | input voltage | | [1] -0.5 | +4.6 | V |
| I_{OK} | output clamping current | $V_O < 0$ V | -50 | - | mA |
| V_O | output voltage | Active mode | [1][2][3] -0.5 | $V_{CCO} + 0.5$ | V |
| | | Suspend or 3-state mode | [1] -0.5 | +4.6 | V |
| I_O | output current | $V_O = 0$ V to V_{CCO} | - | ± 50 | mA |
| I_{CC} | supply current | $I_{CC(A)}$ or $I_{CC(B)}$ | - | 100 | mA |
| I_{GND} | ground current | | -100 | - | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40$ °C to +125 °C | [4] - | 250 | mW |

[1] The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] V_{CCO} is the supply voltage associated with the output port.

[3] $V_{CCO} + 0.5$ V should not exceed 4.6 V.

[4] For SC-88 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

For XSON6 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|-------------------------------------|----------------------------|-------|-----------|------|
| $V_{CC(A)}$ | supply voltage A | | 0.8 | 3.6 | V |
| $V_{CC(B)}$ | supply voltage B | | 0.8 | 3.6 | V |
| V_I | input voltage | | 0 | 3.6 | V |
| V_O | output voltage | Active mode | [1] 0 | V_{CCO} | V |
| | | Suspend or 3-state mode | 0 | 3.6 | V |
| T_{amb} | ambient temperature | | -40 | +125 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CCI} = 0.8$ V to 3.6 V | [2] - | 5 | ns/V |

[1] V_{CCO} is the supply voltage associated with the output port.

[2] V_{CCI} is the supply voltage associated with the input port.

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---------------------------------|--|------------------------|--------|-------|------|
| T_{amb} = 25 °C | | | | | | |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} I _O = -1.5 mA; V _{CC(A)} = V _{CC(B)} = 0.8 V | - | 0.69 | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} I _O = 1.5 mA; V _{CC(A)} = V _{CC(B)} = 0.8 V | - | 0.07 | - | V |
| I _I | input leakage current | DIR input; V _I = 0 V to 3.6 V; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V | - | ±0.025 | ±0.25 | µA |
| I _{BHL} | bus hold LOW current | A or B port; V _I = 0.42 V; V _{CC(A)} = V _{CC(B)} = 1.2 V | - | 26 | - | µA |
| I _{BHH} | bus hold HIGH current | A or B port; V _I = 0.78 V; V _{CC(A)} = V _{CC(B)} = 1.2 V | - | -24 | - | µA |
| I _{BHLO} | bus hold LOW overdrive current | A or B port; V _{CC(A)} = V _{CC(B)} = 1.2 V | [1] | 28 | - | µA |
| I _{BHHO} | bus hold HIGH overdrive current | A or B port; V _{CC(A)} = V _{CC(B)} = 1.2 V | [1] | -26 | - | µA |
| I _{OZ} | OFF-state output current | A or B port; V _O = 0 V or V _{CCO} ; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V | [2] | ±0.5 | ±2.5 | µA |
| I _{OFF} | power-off leakage current | A port; V _I or V _O = 0 V to 3.6 V; V _{CC(A)} = 0 V; V _{CC(B)} = 0.8 V to 3.6 V B port; V _I or V _O = 0 V to 3.6 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0.8 V to 3.6 V | - | ±0.1 | ±1 | µA |
| C _I | input capacitance | DIR input; V _I = 0 V or 3.3 V; V _{CC(A)} = V _{CC(B)} = 3.3 V | - | 1 | - | pF |
| C _{I/O} | input/output capacitance | A and B port; suspend mode; V _O = 3.3 V or 0 V; V _{CC(A)} = V _{CC(B)} = 3.3 V | - | 4 | - | pF |
| T_{amb} = -40 °C to +85 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | data input [3] | | | | |
| | | V _{CCI} = 0.8 V | 0.7V _{CCI} | - | - | V |
| | | V _{CCI} = 1.1 V to 1.95 V | 0.65V _{CCI} | - | - | V |
| | | V _{CCI} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CCI} = 3.0 V to 3.6 V | 2 | - | - | V |
| | | DIR input | | | | |
| | | V _{CCI} = 0.8 V | 0.7V _{CC(A)} | - | - | V |
| | | V _{CCI} = 1.1 V to 1.95 V | 0.65V _{CC(A)} | - | - | V |
| | | V _{CCI} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CCI} = 3.0 V to 3.6 V | 2 | - | - | V |

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--|---------------------------|--|------|------------------------|------------------------|------|---|
| V _{IL} | LOW-level input voltage | data input | [3] | | | | |
| | | V _{CCI} = 0.8 V | - | - | 0.3V _{CCI} | V | |
| | | V _{CCI} = 1.1 V to 1.95 V | - | - | 0.35V _{CCI} | V | |
| | | V _{CCI} = 2.3 V to 2.7 V | - | - | 0.7 | V | |
| | | V _{CCI} = 3.0 V to 3.6 V | - | - | 0.9 | V | |
| | | DIR input | | | | | |
| | | V _{CCI} = 0.8 V | - | - | 0.3V _{CC(A)} | V | |
| | | V _{CCI} = 1.1 V to 1.95 V | - | - | 0.35V _{CC(A)} | V | |
| | | V _{CCI} = 2.3 V to 2.7 V | - | - | 0.7 | V | |
| | | V _{CCI} = 3.0 V to 3.6 V | - | - | 0.9 | V | |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | | I _O = -100 μA; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V | [2] | V _{CCO} - 0.1 | - | - | V |
| | | I _O = -3 mA; V _{CC(A)} = V _{CC(B)} = 1.1 V | 0.85 | - | - | V | |
| | | I _O = -6 mA; V _{CC(A)} = V _{CC(B)} = 1.4 V | 1.05 | - | - | V | |
| | | I _O = -8 mA; V _{CC(A)} = V _{CC(B)} = 1.65 V | 1.2 | - | - | V | |
| | | I _O = -9 mA; V _{CC(A)} = V _{CC(B)} = 2.3 V | 1.75 | - | - | V | |
| I _O = -12 mA; V _{CC(A)} = V _{CC(B)} = 3.0 V | 2.3 | - | - | V | | | |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | | I _O = 100 μA; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V | - | - | 0.1 | V | |
| | | I _O = 3 mA; V _{CC(A)} = V _{CC(B)} = 1.1 V | - | - | 0.25 | V | |
| | | I _O = 6 mA; V _{CC(A)} = V _{CC(B)} = 1.4 V | - | - | 0.35 | V | |
| | | I _O = 8 mA; V _{CC(A)} = V _{CC(B)} = 1.65 V | - | - | 0.45 | V | |
| | | I _O = 9 mA; V _{CC(A)} = V _{CC(B)} = 2.3 V | - | - | 0.55 | V | |
| I _O = 12 mA; V _{CC(A)} = V _{CC(B)} = 3.0 V | - | - | 0.7 | V | | | |
| I _I | input leakage current | DIR input; V _I = 0 V to 3.6 V; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V | - | - | ±1 | μA | |
| I _{BHL} | bus hold LOW current | A or B port | | | | | |
| | | V _I = 0.49 V; V _{CC(A)} = V _{CC(B)} = 1.4 V | 15 | - | - | μA | |
| | | V _I = 0.58 V; V _{CC(A)} = V _{CC(B)} = 1.65 V | 25 | - | - | μA | |
| | | V _I = 0.70 V; V _{CC(A)} = V _{CC(B)} = 2.3 V | 45 | - | - | μA | |
| V _I = 0.80 V; V _{CC(A)} = V _{CC(B)} = 3.0 V | 100 | - | - | μA | | | |
| I _{BHH} | bus hold HIGH current | A or B port | | | | | |
| | | V _I = 0.91 V; V _{CC(A)} = V _{CC(B)} = 1.4 V | -15 | - | - | μA | |
| | | V _I = 1.07 V; V _{CC(A)} = V _{CC(B)} = 1.65 V | -25 | - | - | μA | |
| | | V _I = 1.60 V; V _{CC(A)} = V _{CC(B)} = 2.3 V | -45 | - | - | μA | |
| V _I = 2.00 V; V _{CC(A)} = V _{CC(B)} = 3.0 V | -100 | - | - | μA | | | |

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | | |
|--|---------------------------------|---|---------------------------|---|----------------|---|-----|----|
| I _{BHLO} | bus hold LOW overdrive current | A or B port | [1] | | | | | |
| | | V _{CC(A)} = V _{CC(B)} = 1.6 V | 125 | - | - | μA | | |
| | | V _{CC(A)} = V _{CC(B)} = 1.95 V | 200 | - | - | μA | | |
| | | V _{CC(A)} = V _{CC(B)} = 2.7 V | 300 | - | - | μA | | |
| I _{BHHO} | bus hold HIGH overdrive current | A or B port | [1] | | | | | |
| | | V _{CC(A)} = V _{CC(B)} = 1.6 V | -125 | - | - | μA | | |
| | | V _{CC(A)} = V _{CC(B)} = 1.95 V | -200 | - | - | μA | | |
| | | V _{CC(A)} = V _{CC(B)} = 2.7 V | -300 | - | - | μA | | |
| I _{OZ} | OFF-state output current | A or B port; V _O = 0 V or V _{CCO} ; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V | [2] | - | - | ±5 | μA | |
| | | I _{OFF} | power-off leakage current | A port; V _I or V _O = 0 V to 3.6 V; V _{CC(A)} = 0 V; V _{CC(B)} = 0.8 V to 3.6 V | - | - | ±5 | μA |
| | | | | B port; V _I or V _O = 0 V to 3.6 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0.8 V to 3.6 V | - | - | ±5 | μA |
| | | | | I _{CC} | supply current | A port; V _I = 0 V or V _{CCI} ; I _O = 0 A | [3] | |
| V _{CC(A)} = 0.8 V to 3.6 V; V _{CC(B)} = 0.8 V to 3.6 V | - | - | 8.0 | | | μA | | |
| V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V | - | - | 8.0 | | | μA | | |
| V _{CC(A)} = 0 V; V _{CC(B)} = 3.6 V | -2 | 0 | - | | | μA | | |
| B port; V _I = 0 V or V _{CCI} ; I _O = 0 A | [3] | | | | | | | |
| V _{CC(A)} = 0.8 V to 3.6 V; V _{CC(B)} = 0.8 V to 3.6 V | - | - | 8.0 | | | μA | | |
| V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V | -2 | 0 | - | | | μA | | |
| V _{CC(A)} = 0 V; V _{CC(B)} = 3.6 V | - | - | 8.0 | | | μA | | |
| A plus B port (I _{CC(A)} + I _{CC(B)}); I _O = 0 A; V _I = GND or V _{CCI} ; V _{CC(A)} = 0.8 V to 3.6 V; V _{CC(B)} = 0.8 V to 3.6 V | [3] | - | - | 16 | μA | | | |
| T_{amb} = -40 °C to +125 °C | | | | | | | | |
| V _{IH} | HIGH-level input voltage | data input | [3] | | | | | |
| | | V _{CCI} = 0.8 V | 0.7V _{CCI} | - | - | V | | |
| | | V _{CCI} = 1.1 V to 1.95 V | 0.65V _{CCI} | - | - | V | | |
| | | V _{CCI} = 2.3 V to 2.7 V | 1.6 | - | - | V | | |
| | | V _{CCI} = 3.0 V to 3.6 V | 2 | - | - | V | | |
| | | DIR input | | | | | | |
| | | V _{CCI} = 0.8 V | 0.7V _{CC(A)} | - | - | V | | |
| | | V _{CCI} = 1.1 V to 1.95 V | 0.65V _{CC(A)} | - | - | V | | |
| | | V _{CCI} = 2.3 V to 2.7 V | 1.6 | - | - | V | | |
| | | V _{CCI} = 3.0 V to 3.6 V | 2 | - | - | V | | |

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|------------------|---------------------------|--|------|------------------------|------------------------|------|---|
| V _{IL} | LOW-level input voltage | data input | [3] | | | | |
| | | V _{CCI} = 0.8 V | - | - | 0.3V _{CCI} | V | |
| | | V _{CCI} = 1.1 V to 1.95 V | - | - | 0.35V _{CCI} | V | |
| | | V _{CCI} = 2.3 V to 2.7 V | - | - | 0.7 | V | |
| | | V _{CCI} = 3.0 V to 3.6 V | - | - | 0.9 | V | |
| | | DIR input | | | | | |
| | | V _{CCI} = 0.8 V | - | - | 0.3V _{CC(A)} | V | |
| | | V _{CCI} = 1.1 V to 1.95 V | - | - | 0.35V _{CC(A)} | V | |
| | | V _{CCI} = 2.3 V to 2.7 V | - | - | 0.7 | V | |
| | | V _{CCI} = 3.0 V to 3.6 V | - | - | 0.9 | V | |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | | I _O = -100 μA; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V | [2] | V _{CCO} - 0.1 | - | - | V |
| | | I _O = -3 mA; V _{CC(A)} = V _{CC(B)} = 1.1 V | 0.85 | - | - | V | |
| | | I _O = -6 mA; V _{CC(A)} = V _{CC(B)} = 1.4 V | 1.05 | - | - | V | |
| | | I _O = -8 mA; V _{CC(A)} = V _{CC(B)} = 1.65 V | 1.2 | - | - | V | |
| | | I _O = -9 mA; V _{CC(A)} = V _{CC(B)} = 2.3 V | 1.75 | - | - | V | |
| | | I _O = -12 mA; V _{CC(A)} = V _{CC(B)} = 3.0 V | 2.3 | - | - | V | |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | | I _O = 100 μA; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V | - | - | 0.1 | V | |
| | | I _O = 3 mA; V _{CC(A)} = V _{CC(B)} = 1.1 V | - | - | 0.25 | V | |
| | | I _O = 6 mA; V _{CC(A)} = V _{CC(B)} = 1.4 V | - | - | 0.35 | V | |
| | | I _O = 8 mA; V _{CC(A)} = V _{CC(B)} = 1.65 V | - | - | 0.45 | V | |
| | | I _O = 9 mA; V _{CC(A)} = V _{CC(B)} = 2.3 V | - | - | 0.55 | V | |
| | | I _O = 12 mA; V _{CC(A)} = V _{CC(B)} = 3.0 V | - | - | 0.7 | V | |
| I _I | input leakage current | DIR input; V _I = 0 V to 3.6 V; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V | - | - | ±1.5 | μA | |
| I _{BHL} | bus hold LOW current | A or B port | | | | | |
| | | V _I = 0.49 V; V _{CC(A)} = V _{CC(B)} = 1.4 V | 15 | - | - | μA | |
| | | V _I = 0.58 V; V _{CC(A)} = V _{CC(B)} = 1.65 V | 25 | - | - | μA | |
| | | V _I = 0.70 V; V _{CC(A)} = V _{CC(B)} = 2.3 V | 45 | - | - | μA | |
| | | V _I = 0.80 V; V _{CC(A)} = V _{CC(B)} = 3.0 V | 90 | - | - | μA | |
| I _{BHH} | bus hold HIGH current | A or B port | | | | | |
| | | V _I = 0.91 V; V _{CC(A)} = V _{CC(B)} = 1.4 V | -15 | - | - | μA | |
| | | V _I = 1.07 V; V _{CC(A)} = V _{CC(B)} = 1.65 V | -25 | - | - | μA | |
| | | V _I = 1.60 V; V _{CC(A)} = V _{CC(B)} = 2.3 V | -45 | - | - | μA | |
| | | V _I = 2.00 V; V _{CC(A)} = V _{CC(B)} = 3.0 V | -100 | - | - | μA | |

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | | |
|---|---------------------------------|--|---------------------------|--|----------------|---|-----|----|
| I _{BHLO} | bus hold LOW overdrive current | A or B port [1] | | | | | | |
| | | V _{CC(A)} = V _{CC(B)} = 1.6 V | 125 | - | - | μA | | |
| | | V _{CC(A)} = V _{CC(B)} = 1.95 V | 200 | - | - | μA | | |
| | | V _{CC(A)} = V _{CC(B)} = 2.7 V | 300 | - | - | μA | | |
| I _{BHHO} | bus hold HIGH overdrive current | A or B port [1] | | | | | | |
| | | V _{CC(A)} = V _{CC(B)} = 1.6 V | -125 | - | - | μA | | |
| | | V _{CC(A)} = V _{CC(B)} = 1.95 V | -200 | - | - | μA | | |
| | | V _{CC(A)} = V _{CC(B)} = 2.7 V | -300 | - | - | μA | | |
| I _{OZ} | OFF-state output current | A or B port; V _O = 0 V or V _{CCO} ; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V [2] | - | - | ±7.5 | μA | | |
| | | I _{OFF} | power-off leakage current | A port; V _I or V _O = 0 V to 3.6 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0.8 V to 3.6 V | - | - | ±35 | μA |
| | | | | B port; V _I or V _O = 0 V to 3.6 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0.8 V to 3.6 V | - | - | ±35 | μA |
| | | | | I _{CC} | supply current | A port; V _I = 0 V or V _{CCI} ; I _O = 0 A [3] | | |
| V _{CC(A)} = 0.8 V to 3.6 V; V _{CC(B)} = 0.8 V to 3.6 V | - | - | 12 | | | μA | | |
| V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V | - | - | 12 | | | μA | | |
| V _{CC(A)} = 0 V; V _{CC(B)} = 3.6 V | -8 | 0 | - | | | μA | | |
| B port; V _I = 0 V or V _{CCI} ; I _O = 0 A [3] | | | | | | | | |
| V _{CC(A)} = 0.8 V to 3.6 V; V _{CC(B)} = 0.8 V to 3.6 V | - | - | 12 | | | μA | | |
| V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V | -8 | 0 | - | | | μA | | |
| V _{CC(A)} = 0 V; V _{CC(B)} = 3.6 V | - | - | 12 | | | μA | | |
| A plus B port (I _{CC(A)} + I _{CC(B)}); I _O = 0 A; V _I = GND or V _{CCI} ; V _{CC(A)} = 0.8 V to 3.6 V; V _{CC(B)} = 0.8 V to 3.6 V [3] | - | - | 24 | μA | | | | |

[1] In order to guarantee the node switches, an external driver must source/sink at least I_{BHLO} / I_{BHHO} when the input is in the range V_{IL} to V_{IH}.

[2] V_{CCO} is the supply voltage associated with the output port.

[3] V_{CCI} is the supply voltage associated with the data input port.

11. Dynamic characteristics

Table 8. Typical dynamic characteristics at $V_{CC(A)} = 0.8\text{ V}$ and $T_{amb} = 25\text{ °C}$ [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#); for wave forms see [Figure 5](#) and [Figure 6](#)

| Symbol | Parameter | Conditions | $V_{CC(B)}$ | | | | | | Unit |
|-----------|-------------------|------------|-------------|-------|-------|-------|-------|-------|------|
| | | | 0.8 V | 1.2 V | 1.5 V | 1.8 V | 2.5 V | 3.3 V | |
| t_{pd} | propagation delay | A to B | 15.8 | 8.4 | 8.0 | 8.0 | 8.7 | 9.5 | ns |
| | | B to A | 15.8 | 12.7 | 12.4 | 12.2 | 12.0 | 11.8 | ns |
| t_{dis} | disable time | DIR to A | 12.2 | 12.2 | 12.2 | 12.2 | 12.2 | 12.2 | ns |
| | | DIR to B | 11.7 | 7.9 | 7.6 | 8.2 | 8.7 | 10.2 | ns |
| t_{en} | enable time | DIR to A | 27.5 | 20.6 | 20.0 | 20.4 | 20.7 | 22.0 | ns |
| | | DIR to B | 28.0 | 20.6 | 20.2 | 20.2 | 20.9 | 21.7 | ns |

[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .
 t_{en} is a calculated value using the formula shown in [Section 13.4 "Enable times"](#)

Table 9. Typical dynamic characteristics at $V_{CC(B)} = 0.8\text{ V}$ and $T_{amb} = 25\text{ °C}$ [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#); for wave forms see [Figure 5](#) and [Figure 6](#)

| Symbol | Parameter | Conditions | $V_{CC(A)}$ | | | | | | Unit |
|-----------|-------------------|------------|-------------|-------|-------|-------|-------|-------|------|
| | | | 0.8 V | 1.2 V | 1.5 V | 1.8 V | 2.5 V | 3.3 V | |
| t_{pd} | propagation delay | A to B | 15.8 | 12.7 | 12.4 | 12.2 | 12.0 | 11.8 | ns |
| | | B to A | 15.8 | 8.4 | 8.0 | 8.0 | 8.7 | 9.5 | ns |
| t_{dis} | disable time | DIR to A | 12.2 | 4.9 | 3.8 | 3.7 | 2.8 | 3.4 | ns |
| | | DIR to B | 11.7 | 9.2 | 9.0 | 8.8 | 8.7 | 8.6 | ns |
| t_{en} | enable time | DIR to A | 27.5 | 17.6 | 17.0 | 16.8 | 17.4 | 18.1 | ns |
| | | DIR to B | 28.0 | 17.6 | 16.2 | 15.9 | 14.8 | 15.2 | ns |

[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .
 t_{en} is a calculated value using the formula shown in [Section 13.4 "Enable times"](#)

Table 10. Typical power dissipation capacitance at $V_{CC(A)} = V_{CC(B)}$ and $T_{amb} = 25\text{ °C}$ [1][2]

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | $V_{CC(A)}$ and $V_{CC(B)}$ | | | | | | Unit |
|----------|-------------------------------|---|-----------------------------|-------|-------|-------|-------|-------|------|
| | | | 0.8 V | 1.2 V | 1.5 V | 1.8 V | 2.5 V | 3.3 V | |
| C_{PD} | power dissipation capacitance | A port: (direction A to B); B port: (direction B to A) | 1 | 2 | 2 | 2 | 2 | 2 | pF |
| | | A port: (direction B to A); B port: (direction A to B) | 9 | 11 | 11 | 12 | 14 | 17 | pF |

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

[2] $f_i = 10\text{ MHz}$; $V_i = \text{GND to } V_{CC}$; $t_r = t_f = 1\text{ ns}$; $C_L = 0\text{ pF}$; $R_L = \infty\ \Omega$.

Table 11. Dynamic characteristics for temperature range –40 °C to +85 °C [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#); for wave forms see [Figure 5](#) and [Figure 6](#).

| Symbol | Parameter | Conditions | V _{CC(B)} | | | | | | | | | | Unit |
|---|-------------------|------------|--------------------|------|---------------|------|----------------|------|---------------|------|---------------|------|------|
| | | | 1.2 V ± 0.1 V | | 1.5 V ± 0.1 V | | 1.8 V ± 0.15 V | | 2.5 V ± 0.2 V | | 3.3 V ± 0.3 V | | |
| | | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | |
| V_{CC(A)} = 1.1 V to 1.3 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 9.0 | 0.7 | 6.8 | 0.6 | 6.1 | 0.5 | 5.7 | 0.5 | 6.1 | ns |
| | | B to A | 1.0 | 9.0 | 0.8 | 8.0 | 0.7 | 7.7 | 0.6 | 7.2 | 0.5 | 7.1 | ns |
| t _{dis} | disable time | DIR to A | 2.2 | 8.8 | 2.2 | 8.8 | 2.2 | 8.8 | 2.2 | 8.8 | 2.2 | 8.8 | ns |
| | | DIR to B | 2.2 | 8.4 | 1.8 | 6.7 | 2.0 | 6.9 | 1.7 | 6.2 | 2.4 | 7.2 | ns |
| t _{en} | enable time | DIR to A | - | 17.4 | - | 14.7 | - | 14.6 | - | 13.4 | - | 14.3 | ns |
| | | DIR to B | - | 17.8 | - | 15.6 | - | 14.9 | - | 14.5 | - | 14.9 | ns |
| V_{CC(A)} = 1.4 V to 1.6 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 8.0 | 0.7 | 5.4 | 0.6 | 4.6 | 0.5 | 3.7 | 0.5 | 3.5 | ns |
| | | B to A | 1.0 | 6.8 | 0.8 | 5.4 | 0.7 | 5.1 | 0.6 | 4.7 | 0.5 | 4.5 | ns |
| t _{dis} | disable time | DIR to A | 1.6 | 6.3 | 1.6 | 6.3 | 1.6 | 6.3 | 1.6 | 6.3 | 1.6 | 6.3 | ns |
| | | DIR to B | 2.0 | 7.6 | 1.8 | 5.9 | 1.6 | 6.0 | 1.2 | 4.8 | 1.7 | 5.5 | ns |
| t _{en} | enable time | DIR to A | - | 14.4 | - | 11.3 | - | 11.1 | - | 9.5 | - | 10.0 | ns |
| | | DIR to B | - | 14.3 | - | 11.7 | - | 10.9 | - | 10.0 | - | 9.8 | ns |
| V_{CC(A)} = 1.65 V to 1.95 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 7.7 | 0.6 | 5.1 | 0.5 | 4.3 | 0.5 | 3.4 | 0.5 | 3.1 | ns |
| | | B to A | 1.0 | 6.1 | 0.7 | 4.6 | 0.5 | 4.4 | 0.5 | 3.9 | 0.5 | 3.7 | ns |
| t _{dis} | disable time | DIR to A | 1.6 | 5.5 | 1.6 | 5.5 | 1.6 | 5.5 | 1.6 | 5.5 | 1.6 | 5.5 | ns |
| | | DIR to B | 1.8 | 7.8 | 1.8 | 5.7 | 1.4 | 5.8 | 1.0 | 4.5 | 1.5 | 5.2 | ns |
| t _{en} | enable time | DIR to A | - | 13.9 | - | 10.3 | - | 10.2 | - | 8.4 | - | 8.9 | ns |
| | | DIR to B | - | 13.2 | - | 10.6 | - | 9.8 | - | 8.9 | - | 8.6 | ns |
| V_{CC(A)} = 2.3 V to 2.7 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 7.2 | 0.5 | 4.7 | 0.5 | 3.9 | 0.5 | 3.0 | 0.5 | 2.6 | ns |
| | | B to A | 1.0 | 5.7 | 0.6 | 3.8 | 0.5 | 3.4 | 0.5 | 3.0 | 0.5 | 2.8 | ns |
| t _{dis} | disable time | DIR to A | 1.5 | 4.2 | 1.5 | 4.2 | 1.5 | 4.2 | 1.5 | 4.2 | 1.5 | 4.2 | ns |
| | | DIR to B | 1.7 | 7.3 | 2.0 | 5.2 | 1.5 | 5.1 | 0.6 | 4.2 | 1.1 | 4.8 | ns |
| t _{en} | enable time | DIR to A | - | 13.0 | - | 9.0 | - | 8.5 | - | 7.2 | - | 7.6 | ns |
| | | DIR to B | - | 11.4 | - | 8.9 | - | 8.1 | - | 7.2 | - | 6.8 | ns |
| V_{CC(A)} = 3.0 V to 3.6 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 7.1 | 0.5 | 4.5 | 0.5 | 3.7 | 0.5 | 2.8 | 0.5 | 2.4 | ns |
| | | B to A | 1.0 | 6.1 | 0.6 | 3.6 | 0.5 | 3.1 | 0.5 | 2.6 | 0.5 | 2.4 | ns |
| t _{dis} | disable time | DIR to A | 1.5 | 4.7 | 1.5 | 4.7 | 1.5 | 4.7 | 1.5 | 4.7 | 1.5 | 4.7 | ns |
| | | DIR to B | 1.7 | 7.2 | 0.7 | 5.5 | 0.6 | 5.5 | 0.7 | 4.1 | 1.7 | 4.7 | ns |
| t _{en} | enable time | DIR to A | - | 13.3 | - | 9.1 | - | 8.6 | - | 6.7 | - | 7.1 | ns |
| | | DIR to B | - | 11.8 | - | 9.2 | - | 8.4 | - | 7.5 | - | 7.1 | ns |

[1] t_{pd} is the same as t_{PLH} and t_{PHL}; t_{dis} is the same as t_{PLZ} and t_{PHZ}; t_{en} is the same as t_{PZL} and t_{PZH}.
t_{en} is a calculated value using the formula shown in [Section 13.4 "Enable times"](#)

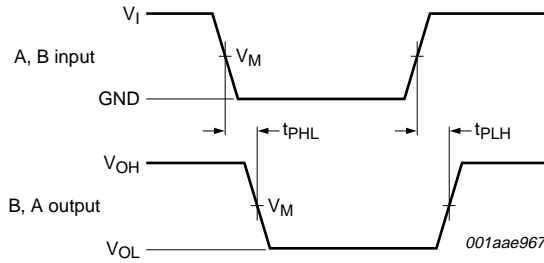
Table 12. Dynamic characteristics for temperature range –40 °C to +125 °C [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#); for wave forms see [Figure 5](#) and [Figure 6](#)

| Symbol | Parameter | Conditions | V _{CC(B)} | | | | | | | | | | Unit |
|---|-------------------|------------|--------------------|------|---------------|------|----------------|------|---------------|------|---------------|------|------|
| | | | 1.2 V ± 0.1 V | | 1.5 V ± 0.1 V | | 1.8 V ± 0.15 V | | 2.5 V ± 0.2 V | | 3.3 V ± 0.3 V | | |
| | | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | |
| V_{CC(A)} = 1.1 V to 1.3 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 9.9 | 0.7 | 7.5 | 0.6 | 6.8 | 0.5 | 6.3 | 0.5 | 6.8 | ns |
| | | B to A | 1.0 | 9.9 | 0.8 | 8.8 | 0.7 | 8.5 | 0.6 | 8.0 | 0.5 | 7.9 | ns |
| t _{dis} | disable time | DIR to A | 2.2 | 9.7 | 2.2 | 9.7 | 2.2 | 9.7 | 2.2 | 9.7 | 2.2 | 9.7 | ns |
| | | DIR to B | 2.2 | 9.2 | 1.8 | 7.4 | 2.0 | 7.6 | 1.7 | 6.9 | 2.4 | 8.0 | ns |
| t _{en} | enable time | DIR to A | - | 19.1 | - | 16.2 | - | 16.1 | - | 14.9 | - | 15.9 | ns |
| | | DIR to B | - | 19.6 | - | 17.2 | - | 16.5 | - | 16.0 | - | 16.5 | ns |
| V_{CC(A)} = 1.4 V to 1.6 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 8.8 | 0.7 | 6.0 | 0.6 | 5.1 | 0.5 | 4.1 | 0.5 | 3.9 | ns |
| | | B to A | 1.0 | 7.5 | 0.8 | 6.0 | 0.7 | 5.7 | 0.6 | 5.2 | 0.5 | 5.0 | ns |
| t _{dis} | disable time | DIR to A | 1.6 | 7.0 | 1.6 | 7.0 | 1.6 | 7.0 | 1.6 | 7.0 | 1.6 | 7.0 | ns |
| | | DIR to B | 2.0 | 8.3 | 1.8 | 6.5 | 1.6 | 6.6 | 1.2 | 5.3 | 1.7 | 6.1 | ns |
| t _{en} | enable time | DIR to A | - | 15.8 | - | 12.5 | - | 12.3 | - | 10.5 | - | 11.1 | ns |
| | | DIR to B | - | 15.8 | - | 13.0 | - | 12.7 | - | 11.1 | - | 10.9 | ns |
| V_{CC(A)} = 1.65 V to 1.95 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 8.5 | 0.6 | 5.7 | 0.5 | 4.8 | 0.5 | 3.8 | 0.5 | 3.5 | ns |
| | | B to A | 1.0 | 6.8 | 0.7 | 5.1 | 0.5 | 4.9 | 0.5 | 4.3 | 0.5 | 4.1 | ns |
| t _{dis} | disable time | DIR to A | 1.6 | 6.1 | 1.6 | 6.1 | 1.6 | 6.1 | 1.6 | 6.1 | 1.6 | 6.1 | ns |
| | | DIR to B | 1.8 | 8.6 | 1.8 | 6.3 | 1.4 | 6.4 | 1.0 | 5.0 | 1.5 | 5.8 | ns |
| t _{en} | enable time | DIR to A | - | 15.4 | - | 11.4 | - | 11.3 | - | 9.3 | - | 9.9 | ns |
| | | DIR to B | - | 14.6 | - | 11.8 | - | 10.9 | - | 9.9 | - | 9.6 | ns |
| V_{CC(A)} = 2.3 V to 2.7 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 8.0 | 0.5 | 5.2 | 0.5 | 4.3 | 0.5 | 3.3 | 0.5 | 2.9 | ns |
| | | B to A | 1.0 | 6.3 | 0.6 | 4.2 | 0.5 | 3.8 | 0.5 | 3.3 | 0.5 | 3.1 | ns |
| t _{dis} | disable time | DIR to A | 1.5 | 4.7 | 1.5 | 4.7 | 1.5 | 4.7 | 1.5 | 4.7 | 1.5 | 4.7 | ns |
| | | DIR to B | 1.7 | 8.0 | 2.0 | 5.8 | 1.5 | 5.7 | 0.6 | 4.7 | 1.1 | 5.3 | ns |
| t _{en} | enable time | DIR to A | - | 14.3 | - | 10.0 | - | 9.5 | - | 8.0 | - | 8.4 | ns |
| | | DIR to B | - | 12.7 | - | 9.9 | - | 9.0 | - | 8.0 | - | 7.6 | ns |
| V_{CC(A)} = 3.0 V to 3.6 V | | | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.0 | 7.9 | 0.5 | 5.0 | 0.5 | 4.1 | 0.5 | 3.1 | 0.5 | 2.7 | ns |
| | | B to A | 1.0 | 6.8 | 0.6 | 4.0 | 0.5 | 3.5 | 0.5 | 2.9 | 0.5 | 2.7 | ns |
| t _{dis} | disable time | DIR to A | 1.5 | 5.2 | 1.5 | 5.2 | 1.5 | 5.2 | 1.5 | 5.2 | 1.5 | 5.2 | ns |
| | | DIR to B | 1.7 | 7.9 | 0.7 | 6.0 | 0.6 | 6.1 | 0.7 | 4.6 | 1.7 | 5.2 | ns |
| t _{en} | enable time | DIR to A | - | 14.7 | - | 10.1 | - | 9.6 | - | 7.5 | - | 7.9 | ns |
| | | DIR to B | - | 13.1 | - | 10.2 | - | 9.3 | - | 8.3 | - | 7.9 | ns |

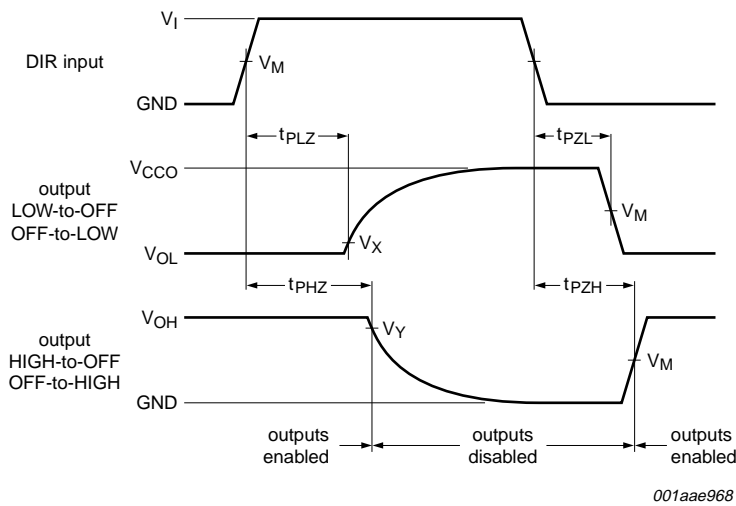
[1] t_{pd} is the same as t_{PLH} and t_{PHL}; t_{dis} is the same as t_{PLZ} and t_{PHZ}; t_{en} is the same as t_{PZL} and t_{PZH}.
t_{en} is a calculated value using the formula shown in [Section 13.4 "Enable times"](#)

12. Waveforms



Measurement points are given in [Table 13](#).
 V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig 5. The data input (A, B) to output (B, A) propagation delay times



Measurement points are given in [Table 13](#).
 V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

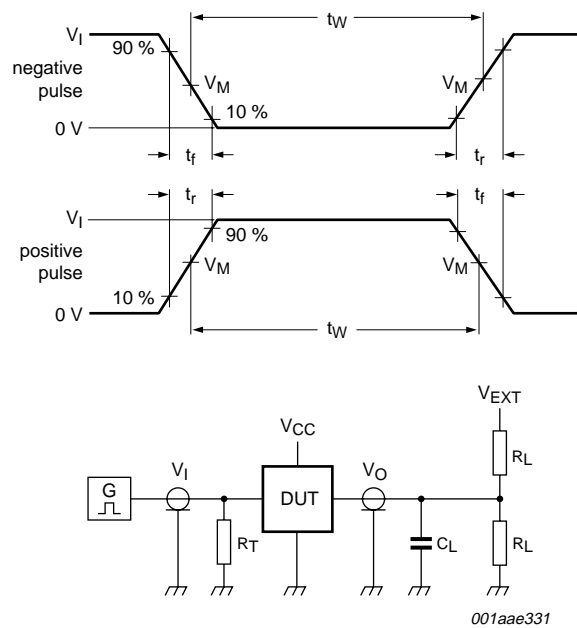
Fig 6. Enable and disable times

Table 13. Measurement points

| Supply voltage | Input ^[1] | Output ^[2] | | |
|------------------------|----------------------|-----------------------|-------------------|-------------------|
| $V_{CC(A)}, V_{CC(B)}$ | V_M | V_M | V_X | V_Y |
| 1.1 V to 1.6 V | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $V_{OL} + 0.1 V$ | $V_{OH} - 0.1 V$ |
| 1.65 V to 2.7 V | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $V_{OL} + 0.15 V$ | $V_{OH} - 0.15 V$ |
| 3.0 V to 3.6 V | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $V_{OL} + 0.3 V$ | $V_{OH} - 0.3 V$ |

[1] V_{CCI} is the supply voltage associated with the data input port.

[2] V_{CCO} is the supply voltage associated with the output port.



Test data is given in [Table 14](#).
 R_L = Load resistance.
 C_L = Load capacitance including jig and probe capacitance.
 R_T = Termination resistance.
 V_{EXT} = External voltage for measuring switching times.

Fig 7. Load circuitry for switching times

Table 14. Test data

| Supply voltage | Input | | Load | | V_{EXT} | | |
|------------------------|----------------------|-------------------------|-------|--------------|--------------------|--------------------|-----------------------------------|
| $V_{CC(A)}, V_{CC(B)}$ | V_I ^[1] | $\Delta t/\Delta V$ | C_L | R_L | t_{PLH}, t_{PHL} | t_{PZH}, t_{PHZ} | t_{PZL}, t_{PLZ} ^[2] |
| 1.1 V to 1.6 V | V_{CCI} | $\leq 1.0 \text{ ns/V}$ | 15 pF | 2 k Ω | open | GND | $2V_{CCO}$ |
| 1.65 V to 2.7 V | V_{CCI} | $\leq 1.0 \text{ ns/V}$ | 15 pF | 2 k Ω | open | GND | $2V_{CCO}$ |
| 3.0 V to 3.6 V | V_{CCI} | $\leq 1.0 \text{ ns/V}$ | 15 pF | 2 k Ω | open | GND | $2V_{CCO}$ |

[1] V_{CCI} is the supply voltage associated with the data input port.

[2] V_{CCO} is the supply voltage associated with the output port.

13. Application information

13.1 Unidirectional logic level-shifting application

The circuit given in [Figure 8](#) is an example of the 74AVCH1T45 being used in an unidirectional logic level-shifting application.

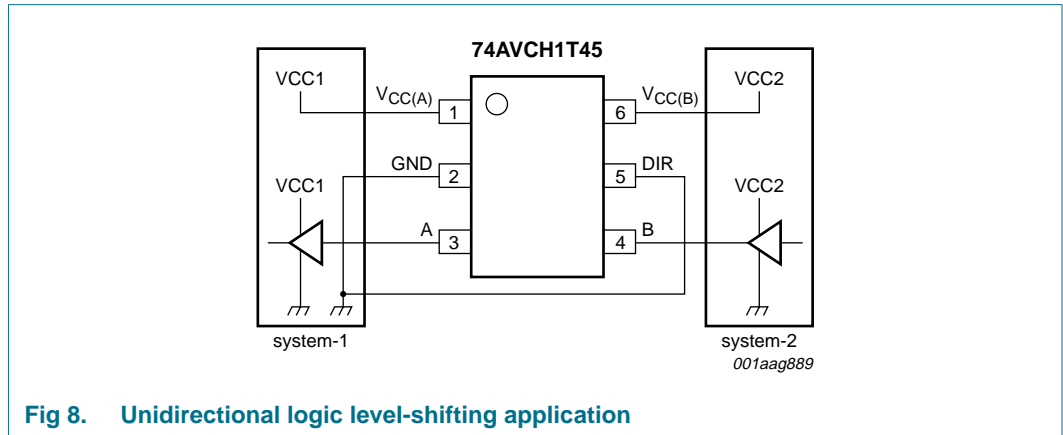


Fig 8. Unidirectional logic level-shifting application

Table 15. Description unidirectional logic level-shifting application

| Pin | Name | Function | Description |
|-----|--------------------|------------------|---|
| 1 | V _{CC(A)} | V _{CC1} | supply voltage of system-1 (0.8 V to 3.6 V) |
| 2 | GND | GND | device GND |
| 3 | A | OUT | output level depends on V _{CC1} voltage |
| 4 | DIR | DIR | the GND (LOW level) determines B port to A port direction |
| 5 | B | IN | input threshold value depends on V _{CC2} voltage |
| 6 | V _{CC(B)} | V _{CC2} | supply voltage of system-2 (0.8 V to 3.6 V) |

13.2 Bidirectional logic level-shifting application

Figure 9 shows the 74AVCH1T45 being used in a bidirectional logic level-shifting application. Since the device does not have an output enable pin, the system designer should take precautions to avoid bus contention between system-1 and system-2 when changing directions.

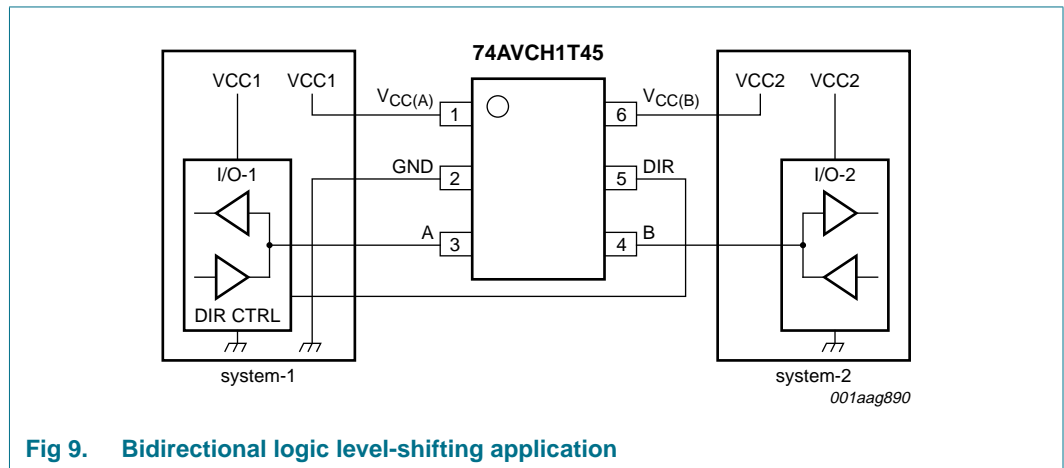


Fig 9. Bidirectional logic level-shifting application

Table 16 gives a sequence that will illustrate data transmission from system-1 to system-2 and then from system-2 to system-1.

Table 16. Description bidirectional logic level-shifting application[1]

| State | DIR CTRL | I/O-1 | I/O-2 | Description |
|-------|----------|--------|--------|---|
| 1 | H | output | input | system-1 data to system-2 |
| 2 | H | Z | Z | system-2 is getting ready to send data to system-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on bus hold. |
| 3 | L | Z | Z | DIR bit is set LOW. I/O-1 and I/O-2 still are disabled. The bus-line state depends on bus hold. |
| 4 | L | input | output | system-2 data to system-1 |

[1] H = HIGH voltage level;
 L = LOW voltage level;
 Z = high-impedance OFF-state.

13.3 Power-up considerations

The device is designed such that no special power-up sequence is required other than GND being applied first.

Table 17. Typical total supply current ($I_{CC(A)} + I_{CC(B)}$)

| $V_{CC(A)}$ | $V_{CC(B)}$ | | | | | | | Unit |
|-------------|-------------|-------|-------|-------|-------|-------|-------|---------|
| | 0 V | 0.8 V | 1.2 V | 1.5 V | 1.8 V | 2.5 V | 3.3 V | |
| 0 V | 0 | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | μA |
| 0.8 V | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | 0.7 | 2.3 | μA |
| 1.2 V | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | 0.3 | 1.4 | μA |
| 1.5 V | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | 0.9 | μA |
| 1.8 V | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | 0.5 | μA |
| 2.5 V | 0.1 | 0.7 | 0.3 | 0.1 | 0.1 | 0.1 | 0.1 | μA |
| 3.3 V | 0.1 | 2.3 | 1.4 | 0.9 | 0.5 | 0.1 | 0.1 | μA |

13.4 Enable times

The enable times for the 74AVCH1T45 are calculate from the following formulas:

- $t_{en} \text{ (DIR to A)} = t_{dis} \text{ (DIR to B)} + t_{pd} \text{ (B to A)}$
- $t_{en} \text{ (DIR to B)} = t_{dis} \text{ (DIR to A)} + t_{pd} \text{ (A to B)}$

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the 74AVCH1T45 initially is transmitting from A to B, then the DIR bit is switched, the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.

14. Package outline

Plastic surface-mounted package; 6 leads

SOT363

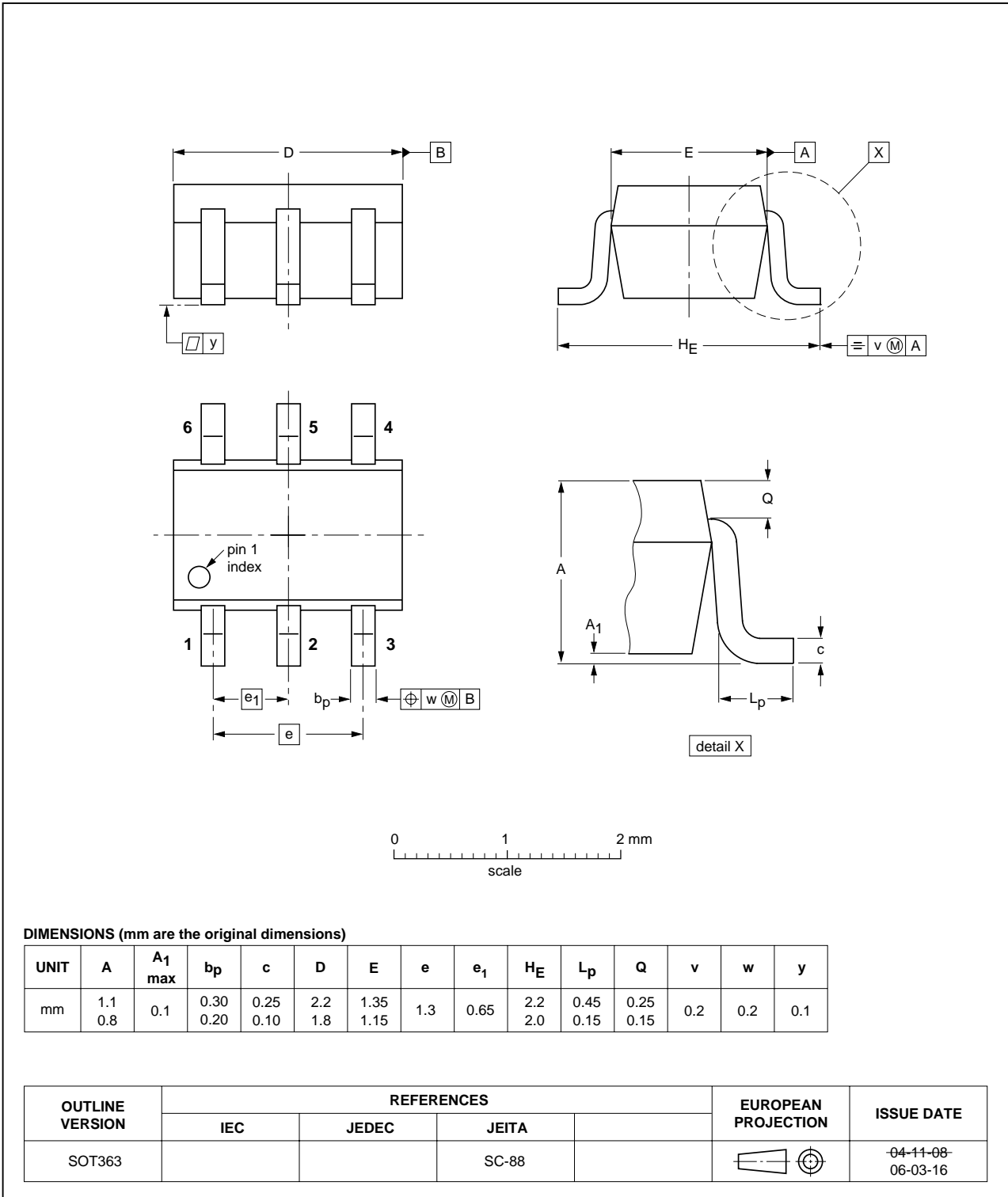


Fig 10. Package outline SOT363 (SC-88)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

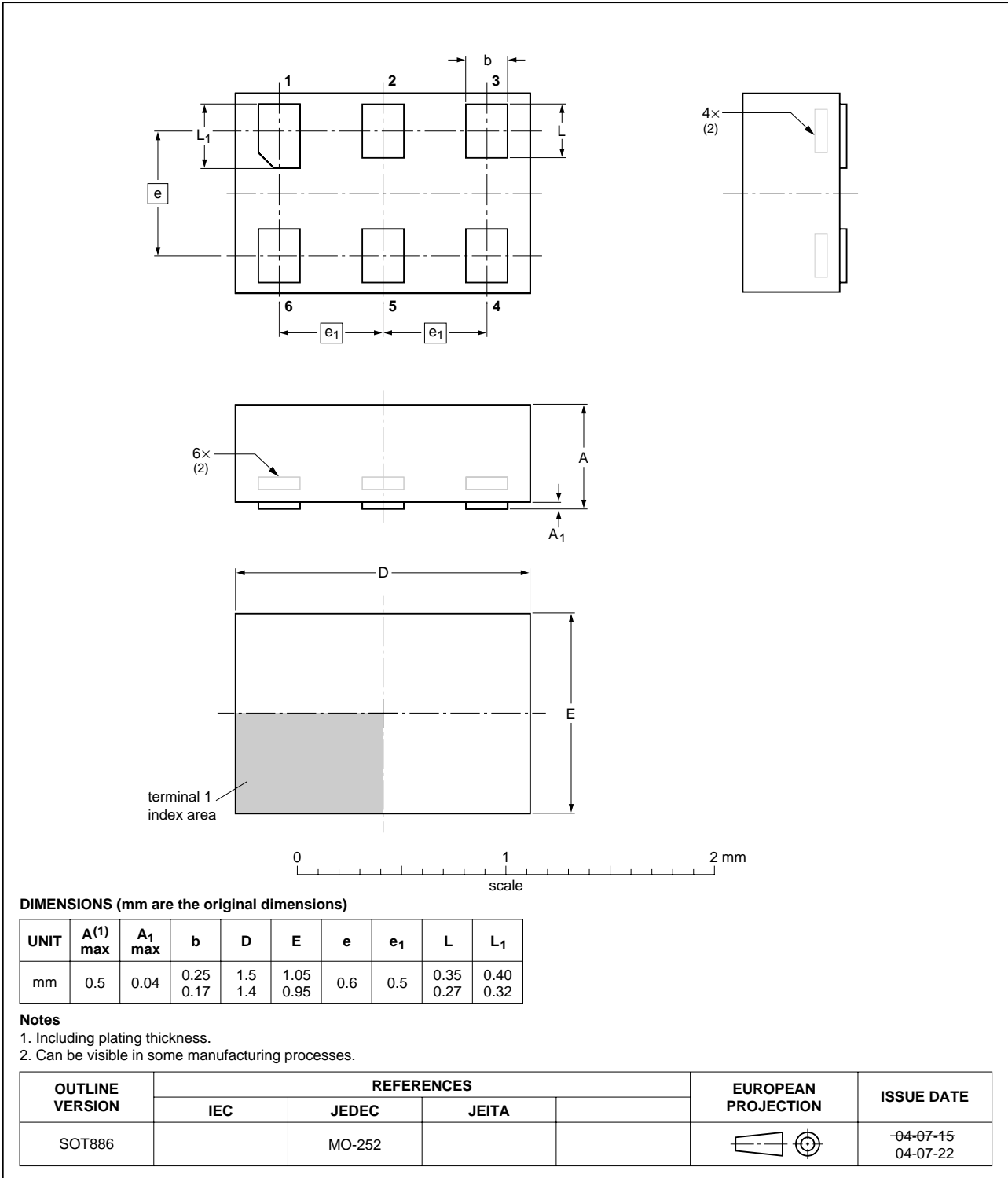


Fig 11. Package outline SOT886 (XSON6)

15. Abbreviations

Table 18. Abbreviations

| Acronym | Description |
|---------|---|
| CDM | Charged Device Model |
| CMOS | Complementary Metal Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |

16. Revision history

Table 19. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--|--------------------|---------------|--------------|
| 74AVCH1T45_2 | 20090505 | Product data sheet | - | 74AVCH1T45_1 |
| Modifications: | • Conditions for I _{CC} changed | | | |
| 74AVCH1T45_1 | 20071025 | Product data sheet | - | - |

17. Legal information

17.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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19. Contents

1 General description 1

2 Features 1

3 Ordering information 2

4 Marking 2

5 Functional diagram 2

6 Pinning information 3

6.1 Pinning 3

6.2 Pin description 3

7 Functional description 3

8 Limiting values 4

9 Recommended operating conditions 4

10 Static characteristics 5

11 Dynamic characteristics 10

12 Waveforms 13

13 Application information 15

13.1 Unidirectional logic level-shifting application . . 15

13.2 Bidirectional logic level-shifting application . . 16

13.3 Power-up considerations 17

13.4 Enable times 17

14 Package outline 18

15 Abbreviations 20

16 Revision history 20

17 Legal information 21

17.1 Data sheet status 21

17.2 Definitions 21

17.3 Disclaimers 21

17.4 Trademarks 21

18 Contact information 21

19 Contents 22

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